

THERMAL PERFORMANCE				
PARAMETER		SYMBOL	ТҮР	UNIT
Junction-to-case thermal resistance	MBRF20L100CT	$R_{\Theta JC}$	5.5	°C/W
	MBRF20L120CT		5.0	°C/W

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_A = 25^{\circ}C$ unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Forward voltage per diode <sup>(1)</sup>	MBRF20L100CT	I <sub>F</sub> = 10A,T <sub>J</sub> = 25°C	V <sub>F</sub>	0.72	0.75	V
	MBRF20L120CT			0.78	0.83	V
	MBRF20L100CT	I <sub>F</sub> = 20A,T <sub>J</sub> = 25°C		0.81	0.85	V
	MBRF20L120CT			0.86	0.90	V
	MBRF20L100CT	I <sub>F</sub> = 10A,T <sub>J</sub> = 125°C		0.58	0.68	V
	MBRF20L120CT			0.63	0.72	V
	MBRF20L100CT	I <sub>F</sub> = 20A,T <sub>J</sub> = 125°C		0.67	0.75	V
	MBRF20L120CT			0.73	0.80	V
Reverse current @ rated V <sub>R</sub> per diode <sup>(2)</sup>	MBRF20L100CT MBRF20L120CT	T <sub>J</sub> = 25°C	I <sub>R</sub>	-	20	μA
	MBRF20L100CT	T <sub>J</sub> = 125°C		-	15	mA
	MBRF20L120CT			-	10	mA

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION		
ORDERING CODE <sup>(1)(2)</sup>	PACKAGE	PACKING
MBRF20LxCT	ITO-220AB	50 / Tube
MBRF20LxCTH	ITO-220AB	50 / Tube

Notes:

1. "x" defines voltage from 100V(MBRF20L100CT) to 120V(MBRF20L120CT)

2. "H" means AEC-Q101 qualified



INSTANTANEOUS REVERSE CURRENT (µA)

# MBRF20L100CT – MBRF20L120CT

Taiwan Semiconductor

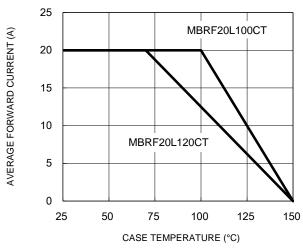
MBRF20L100CT

10

100

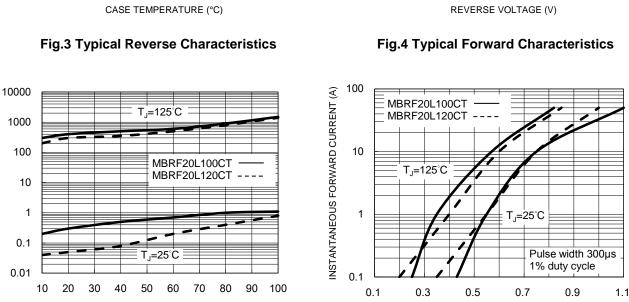
#### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 



PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

Fig.1 Forward Current Derating Curve



10000

1000

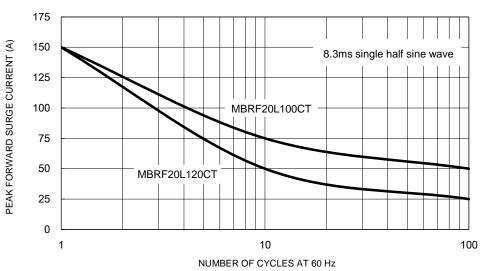
100

10

0.1

CAPACITANCE (pF)

FORWARD VOLTAGE (V)



## Fig.5 Maximum Non-Repetitive Forward Surge Current

Fig.2 Typical Junction Capacitance

+++++

f=1.0MHz Vsig=50mVp-p

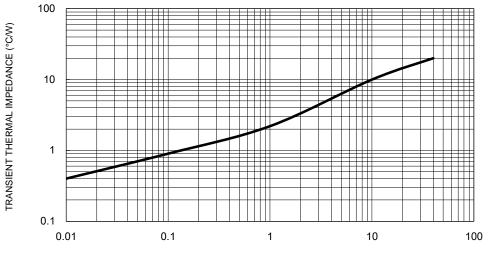
MBRF20L120CT

1



## **CHARACTERISTICS CURVES**

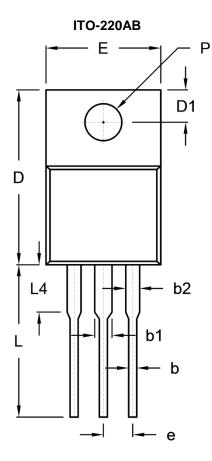
 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

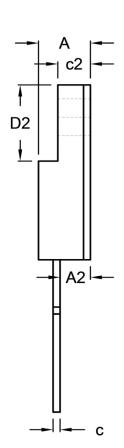


#### Fig.6 Typical Transient Thermal Impedance

PULSE DURATION (s)

## PACKAGE OUTLINE DIMENSIONS





DIM.	Unit (mm)		Unit (	(inch)
	Min.	Max.	Min.	Max.
A	4.30	4.70	0.169	0.185
A2	2.30	2.96	0.091	0.117
b	0.50	0.90	0.020	0.035
b1	-	1.80	-	0.071
b2	0.95	1.45	0.037	0.057
с	0.46	0.76	0.018	0.030
c2	2.50	3.16	0.098	0.124
D	14.80	15.50	0.583	0.610
D1	2.40	3.20	0.094	0.126
D2	6.30	6.90	0.248	0.272
E	9.60	10.30	0.378	0.406
е	2.41	2.67	0.095	0.105
L	12.60	13.80	0.496	0.543
L4	-	4.10	-	0.161
Р	3.00	3.40	0.118	0.134

### **MARKING DIAGRAM**

雪別 GYWW <mark>F</mark>
P/N

P/N	= Marking Code
G	= Green Compound
YWW	= Date Code
F	= Factory Code



## Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf assumes no responsibility or liability for any errors or inaccuracies.

Purchasers are solely responsible for the choice, selection, and use of TSC products and TSC assumes no liability for application assistance or the design of Purchasers' products.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.

# **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Taiwan Semiconductor: MBRF20L100CT MBRF20L120CT MBRF20L120CTH